

AS PER THE TEST REPORT NO. 217/2017-18/PID/NISE DATED 24/01/2018 THE PHOTOVOLTAIC MODULES BEARING MODEL NSA-320 MANUFACTURED AND SUBMITTED BY M/S. NAVITAS GREEN SOLUTIONS PVT. LTD, PLOT NO. B 20/3, ROAD NO. 13-14, HOJIWALA INDUSTRIAL ESTATE, SACHIN - PALSANA HIGHWAY, SURAT - 394230 (GUJARAT), INDIA TESTED AT NISE MEETS THE REQUIREMENT TO PASS THE POTENTIAL INDUCED DEGRADATION TEST AS PER MNRE SPECIFICATIONS FOLLOWING THE TEST PROCEDURE AS PER IEC TS 62804-1: 2015.

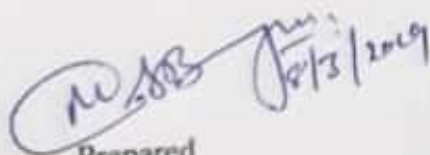
TEST CONDITION: 4 MODULES [2(+V) and 2(-V)] BIASED AT 1000 V AND SUBJECTED TO 3 CYCLES AT 85% RELATIVE HUMIDITY AND 85°C TEMPERATURE FOR 96 HOURS IN AN ENVIRONMENTAL CHAMBER (TEST PROCEDURE AS PER IEC TS 62804-1: 2015)

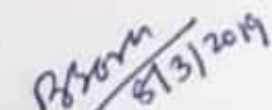
MODEL TESTED: NSA 320


TYPES EXTENDED FOR SIMILARITY WITH MULTI CRYSTALLINE SILICON SOLAR CELL TECHNOLOGY AS PER IEC TS 62804-1: 2015 (MODULES MADE WITH NO CUT CELL AND NO CHANGE IN BILL OF MATERIAL)

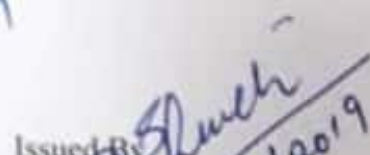
Models Covered: Poly Crystalline Modules- Model Range

- NSAxxx (xxx = 275 - 335, in steps of 5, 72 cells)
- NSAxxx (xxx = 230 - 275, in steps of 5, 60 cells)
- NSAxxx (xxx = 205 - 250, in steps of 5, 54 cells)
- NSAxxx (xxx = 185 - 220, in steps of 5, 48 cells)
- NSAxxx (xxx = 140 - 165, in steps of 5, 36 cells)


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Date.....


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Authorized Signatory
Dr. Chandan Banerjee
(D.D.G. NISE)
Date.....

Issued By 
Date.....

